Complementary Silicon Plastic Power Transistors

DPAK-3 for Surface Mount Applications

Designed for low voltage, low-power, high-gain audio amplifier applications.

Features

- High DC Current Gain
- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("-1" Suffix)
- Low Collector-Emitter Saturation Voltage
- High Current–Gain Bandwidth Product
- Annular Construction for Low Leakage
- Epoxy Meets UL 94 V-0 @ 0.125 in
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|-----------------------------------|--------------|-----------|
| Collector-Base Voltage | V _{CB} | 100 | Vdc |
| Collector–Emitter Voltage | V _{CEO} | 100 | Vdc |
| Emitter-Base Voltage | V _{EB} | 7.0 | Vdc |
| Collector Current – Continuous | Ι _C | 4.0 | Adc |
| Collector Current – Peak | I _{CM} | 8.0 | Adc |
| Base Current | Ι _Β | 1.0 | Adc |
| Total Device Dissipation @ T _C = 25°C Derate above 25°C | P _D | 12.5 0.1 | W W/°C |
| Total Device Dissipation @ $T_A = 25^{\circ}C$ (Note 2) Derate above 25°C | PD | 1.4 0.011 | W W/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -65 to +150 | °C |
| ESD – Human Body Model | HBM | 3B | V |
| ESD – Machine Model | MM | С | V |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

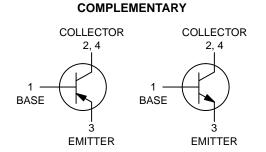


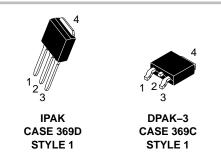


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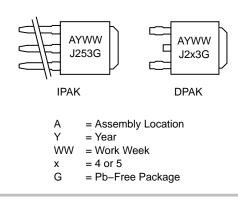
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4.0 A, 100 V, 12.5 W POWER TRANSISTOR





MARKING DIAGRAMS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Value | Unit |
|--|---|------------|------|
| Thermal Resistance Junction-to-Case Junction-to-Ambient (Note 2) | ${\sf R}_{	heta {\sf JC}} \ {\sf R}_{	heta {\sf JA}}$ | 10 89.3 | °C/W |

2. When surface mounted on minimum pad sizes recommended.

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

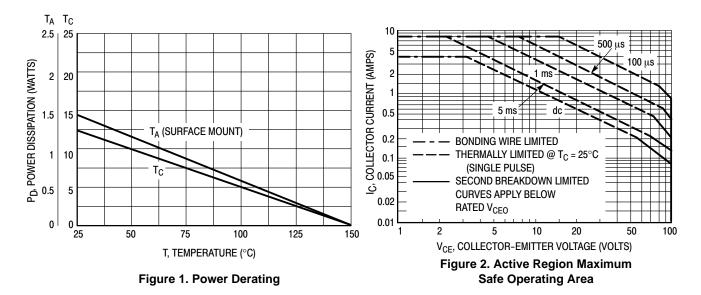
| Characteristic | Symbol | Min | Max | Unit |
|---|-----------------------|----------|------------|--------------|
| OFF CHARACTERISTICS | | | | |
| Collector–Emitter Sustaining Voltage (Note 3) $(I_C = 10 \text{ mAdc}, I_B = 0)$ | V _{CEO(sus)} | 100 | _ | Vdc |
| Collector Cutoff Current $(V_{CB} = 100 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 100 \text{ Vdc}, I_E = 0, T_J = 125^{\circ}\text{C})$ | I _{CBO} | - | 100 100 | nAdc μAdc |
| Emitter Cutoff Current ($V_{BE} = 7.0 \text{ Vdc}, I_C = 0$) | IEBO | - | 100 | nAdc |
| DC Current Gain (Note 3) ($I_C = 200 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$) ($I_C = 1.0 \text{ Adc}, V_{CE} = 1.0 \text{ Vdc}$) | h _{FE} | 40 15 | 180 - | - |
| Collector–Emitter Saturation Voltage (Note 3) ($I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc}$) ($I_C = 1.0 \text{ Adc}, I_B = 100 \text{ mAdc}$) | V _{CE(sat)} | - | 0.3 0.6 | Vdc |
| Base–Emitter Saturation Voltage (Note 3) ($I_C = 2.0 \text{ Adc}, I_B = 200 \text{ mAdc}$) | V _{BE(sat)} | _ | 1.8 | Vdc |
| Base–Emitter On Voltage (Note 3) (I _C = 500 mAdc, V _{CE} = 1.0 Vdc) | V _{BE(on)} | - | 1.5 | Vdc |
| DYNAMIC CHARACTERISTICS | | | | _ |
| Current–Gain – Bandwidth Product (Note 4) (I _C = 100 mAdc, V _{CE} = 10 Vdc, f _{test} = 10 MHz) | f _T | 40 | _ | MHz |
| Output Capacitance | C _{ob} | | | pF |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: Pulse Width = $300 \ \mu$ s, Duty Cycle $\approx 2\%$.

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 $(\dot{V}_{CB} = 10 \text{ Vdc}, I_E = 0, f = 0.1 \text{ MHz})$

4. $f_T = |h_{FE}| \bullet f_{test}$.



There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I_C-V_{CE} limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 2 is based on $T_{J(pk)} = 150^{\circ}C$; T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}C$. $T_{J(pk)}$ may be calculated from the data in Figure 3. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

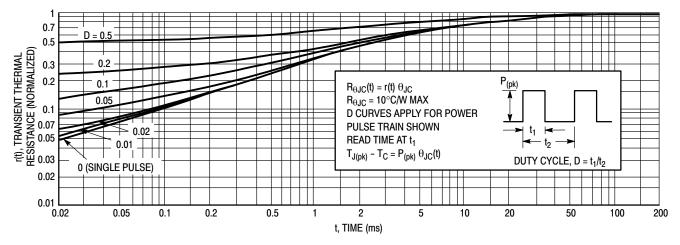


Figure 3. Thermal Response

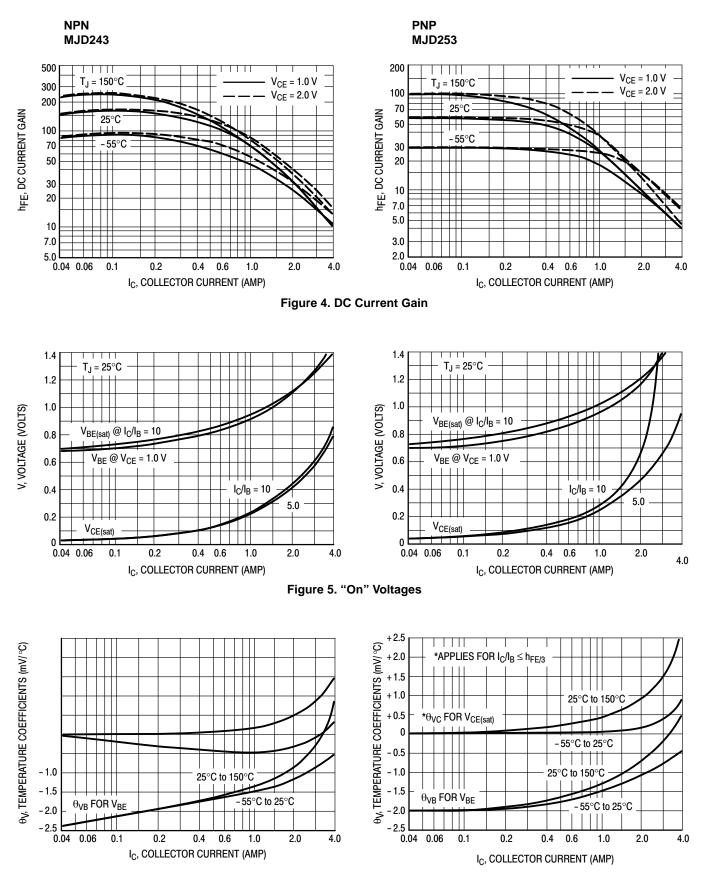
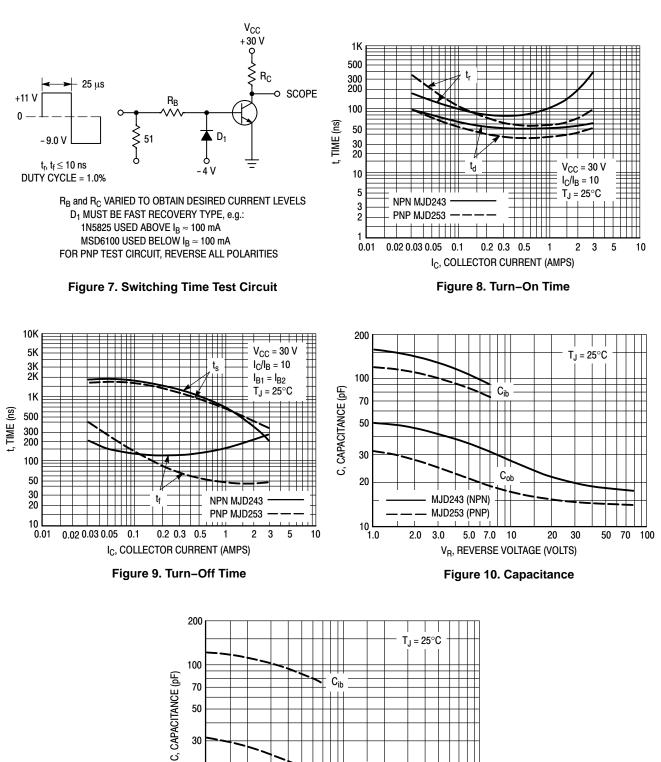
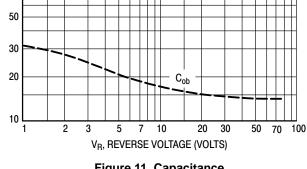


Figure 6. Temperature Coefficients





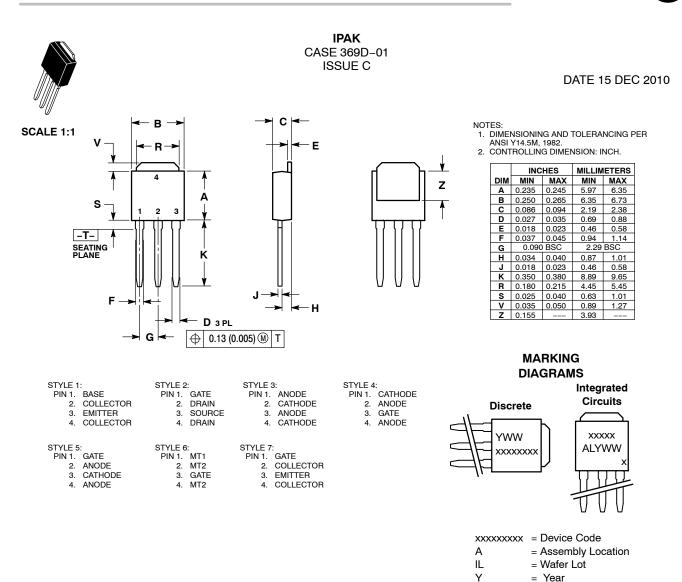
ORDERING INFORMATION

| Device | Package Type | Package | Shipping [†] |
|---------------|---------------------|---------|-----------------------|
| MJD243G | DPAK-3 (Pb-Free) | 369C | 75 Units / Rail |
| MJD243T4G | DPAK–3 (Pb–Free) | 369C | 2,500 / Tape & Reel |
| NJVMJD243T4G* | DPAK–3 (Pb–Free) | 369C | 2,500 / Tape & Reel |
| MJD253–1G | IPAK (Pb–Free) | 369D | 75 Units / Rail |
| MJD253T4G | DPAK-3 (Pb-Free) | 369C | 2,500 / Tape & Reel |
| NJVMJD253T4G* | DPAK–3 (Pb–Free) | 369C | 2,500 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

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|---|-----------------------------|---|-------------|--|
| DESCRIPTION: | IPAK (DPAK INSERTION MOUNT) | | PAGE 1 OF 1 | |
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